



CPH6444

N-Channel Power MOSFET 60V, 4.5A, 78mΩ, Single CPH6

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<http://onsemi.com>

Features

- Low ON-resistance
- Protection diode in 4V drive
- Protection diode in
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

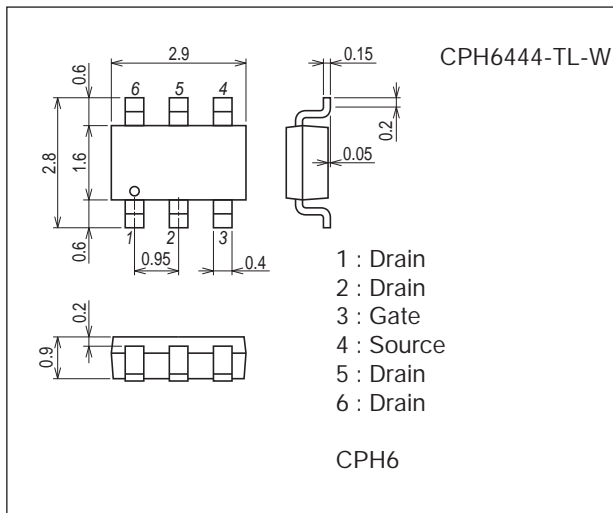
Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V _{DSS}		60	V
Gate to Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		4.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	18	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)	1.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

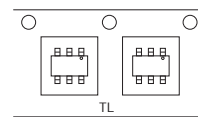
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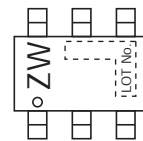
Ordering & Package Information

Device	Package	Shipping	memo
CPH6444-TL-W	CPH6 SC-74, SOT-26, SOT-457	3,000 pcs./reel	Pb-Free and Halogen Free

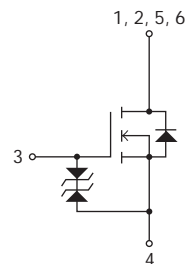
Packing Type: TL



Marking



Electrical Connection

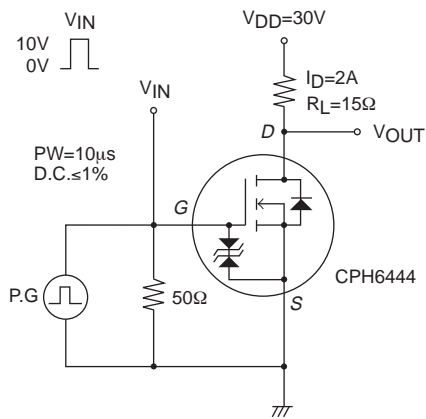


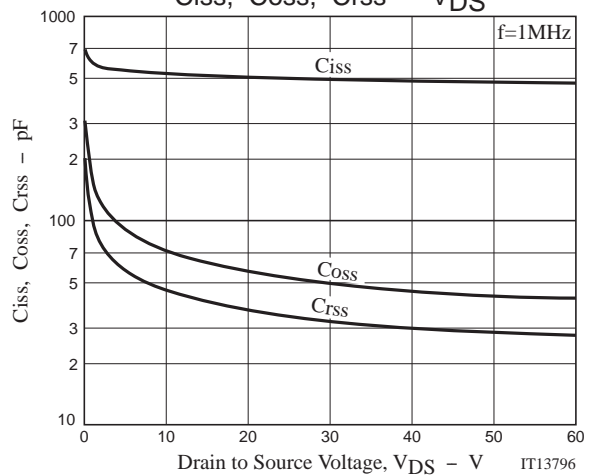
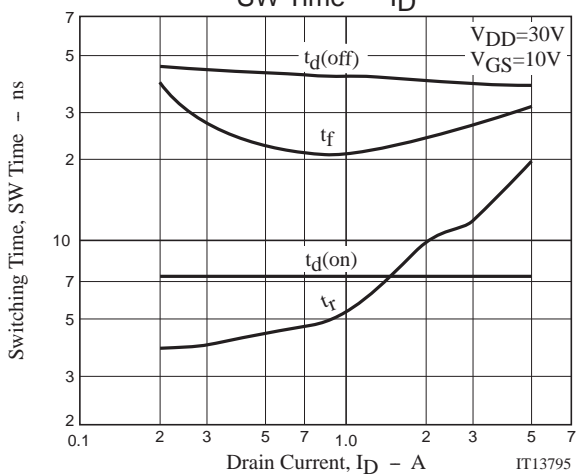
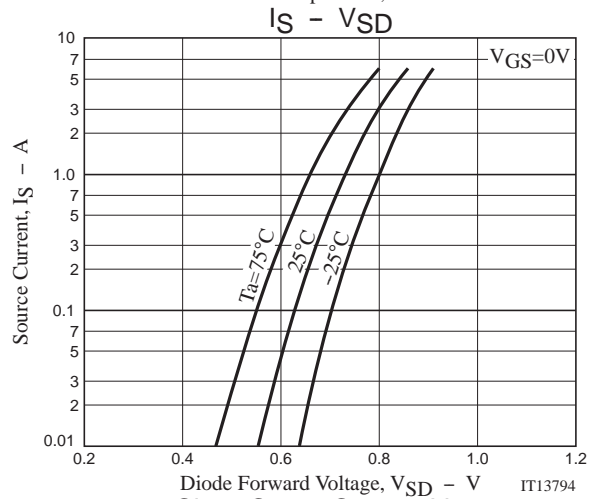
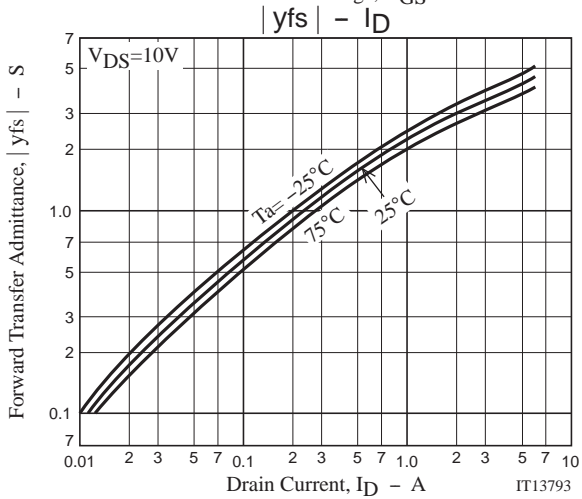
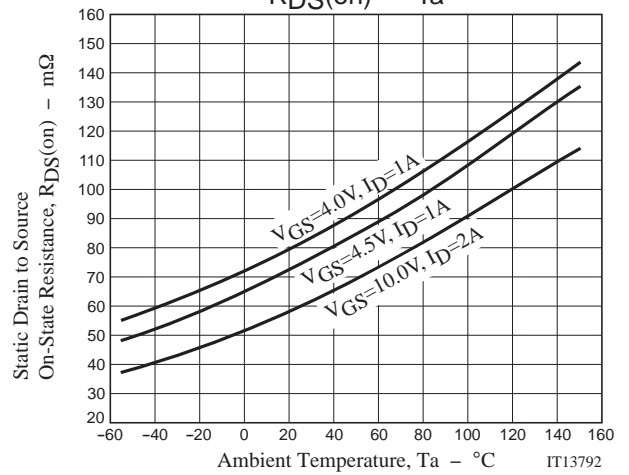
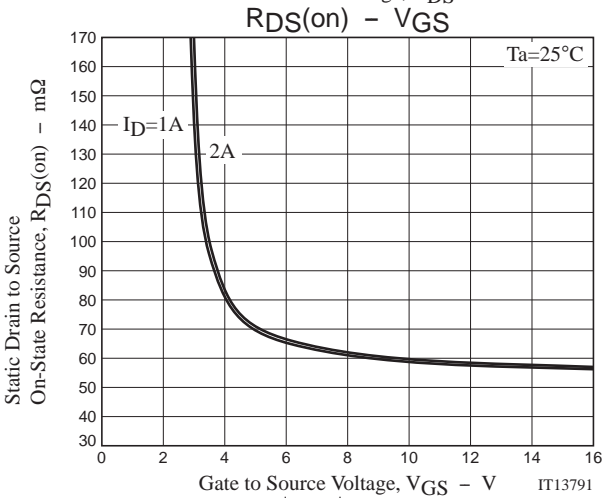
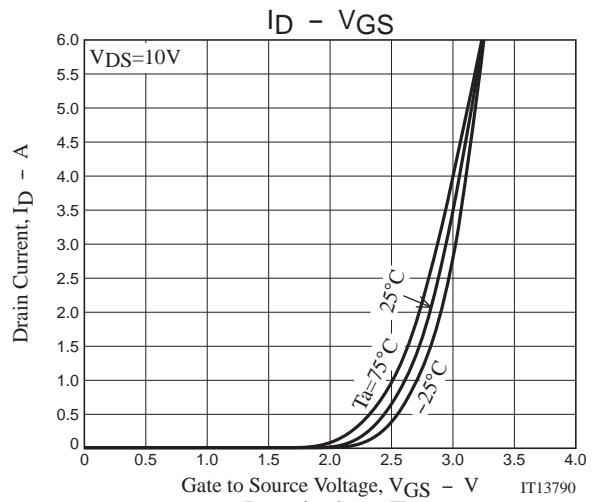
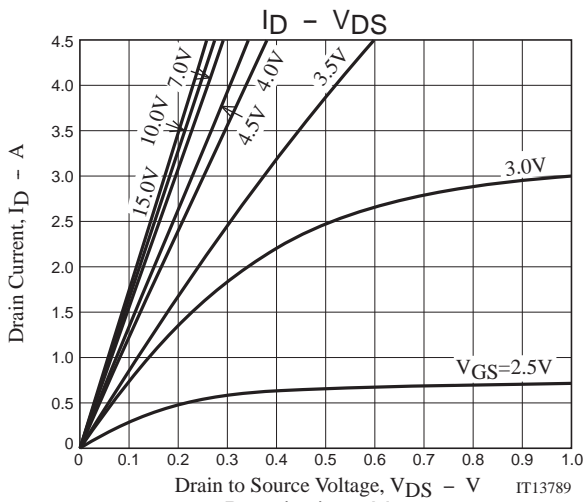
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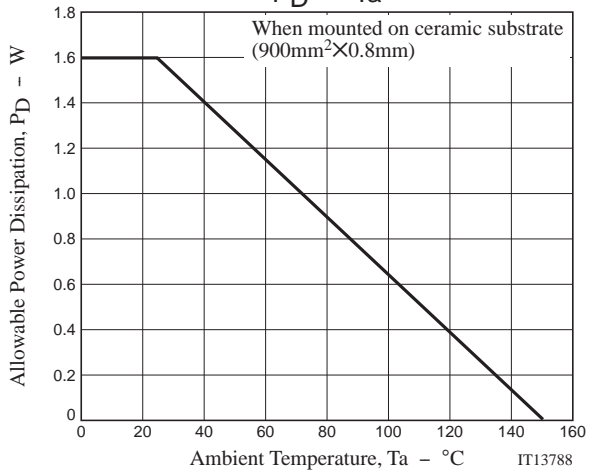
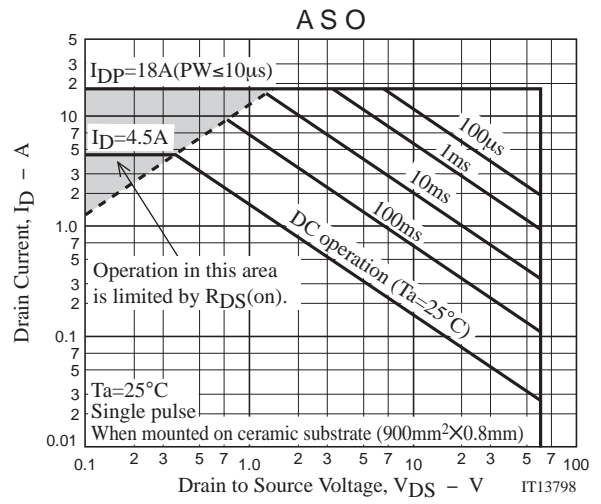
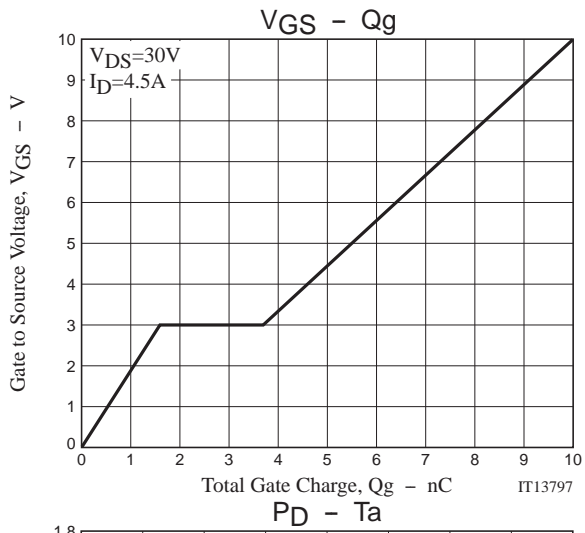
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	60			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V			1	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =2A	1.8	3		S
Static Drain to Source On-State Resistance	R _{DS(on)1}	I _D =2A, V _{GS} =10V		60	78	mΩ
	R _{DS(on)2}	I _D =1A, V _{GS} =4.5V		74	104	mΩ
	R _{DS(on)3}	I _D =1A, V _{GS} =4V		81	114	mΩ
Input Capacitance	C _{iss}	V _{DS} =20V, f=1MHz		505		pF
Output Capacitance	C _{oss}			57		pF
Reverse Transfer Capacitance	C _{rss}			37		pF
Turn-ON Delay Time	t _{d(on)}		See specified Test Circuit.		7.3	
Rise Time	t _r			9.8		ns
Turn-OFF Delay Time	t _{d(off)}			40		ns
Fall Time	t _f			24		ns
Total Gate Charge	Q _g	V _{DS} =30V, V _{GS} =10V, I _D =4.5A			10	
Gate to Source Charge	Q _{gs}			1.6		nC
Gate to Drain "Miller" Charge	Q _{gd}			2.1		nC
Diode Forward Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V		0.83	1.2	V

Switching Time Test Circuit



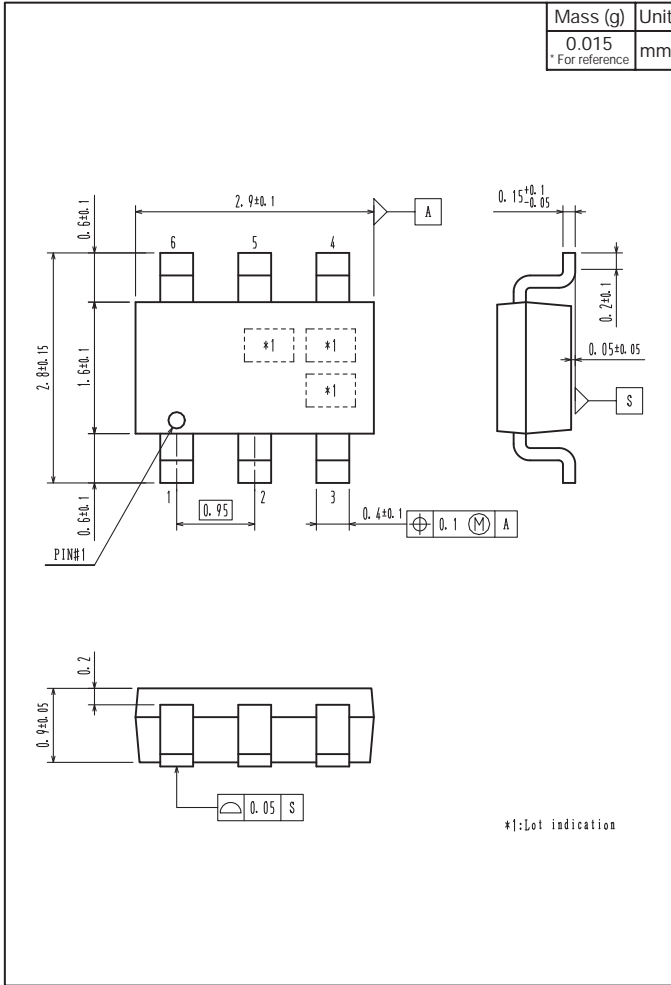




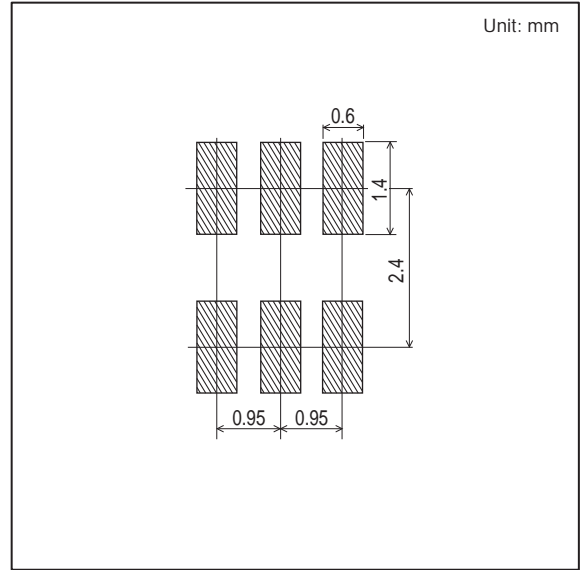
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Outline Drawing

CPH6444-TL-W



Land Pattern Example





Note on usage : Since the CPH6444 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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